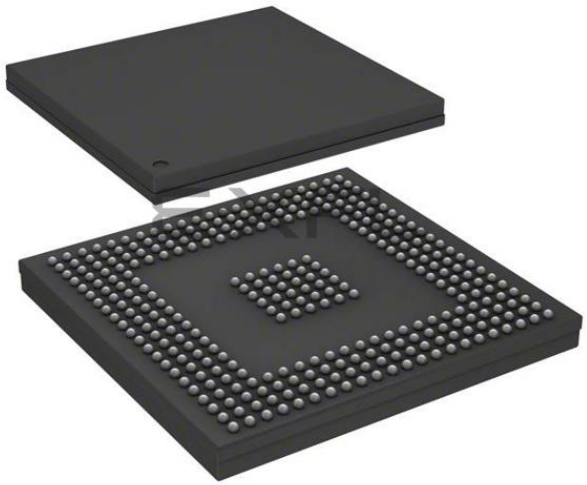

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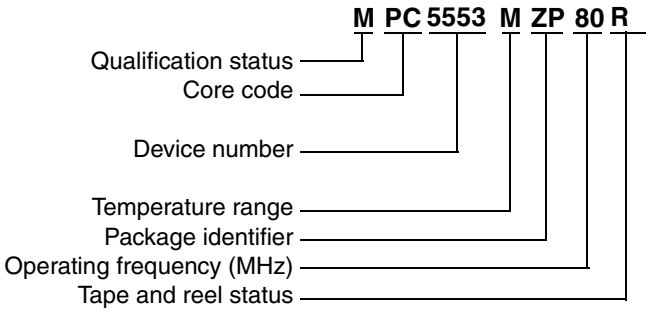
"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	e200z6
Core Size	32-Bit Single-Core
Speed	132MHz
Connectivity	CANbus, EBI/EMI, Ethernet, SCI, SPI
Peripherals	DMA, POR, PWM, WDT
Number of I/O	220
Program Memory Size	1.5MB (1.5M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	64K x 8
Voltage - Supply (Vcc/Vdd)	1.35V ~ 1.65V
Data Converters	A/D 40x12b
Oscillator Type	External
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	324-BBGA
Supplier Device Package	324-PBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc5553mzq132

2 Ordering Information



Temperature Range
M = –40° C to 125° C

Package Identifier
ZP = 416PBGA SnPb
VR = 416PBGA Pb-free
VF = 208MAPBGA SnPb
VM = 208MAPBGA Pb-free
ZQ = 324PBGA SnPb
VZ = 324PBGA Pb-free

Operating Frequency
80 = 80 MHz
112 = 112 MHz
132 = 132 MHz

Tape and Reel Status
R = Tape and reel
(blank) = Trays

Qualification Status
P = Pre qualification
M = Fully spec. qualified, general market flow
S = Fully spec. qualified, automotive flow

Note: Not all options are available on all devices. Refer to Table 1.

Figure 1. MPC5500 Family Part Number Example

Unless noted in this data sheet, all specifications apply from T_L to T_H.

Table 1. Orderable Part Numbers

Freescale Part Number[1]	Package Description	Speed (MHz)		Operating Temperature [2]	
		Nominal	Max. [3] (f_{MAX})	Min. (T_L)	Max. (T_H)
MPC5553MVR132	MPC5553 416 package Lead-free (Pb-free)	132	132	–40° C	125° C
MPC5553MVR112		112	114		
MPC5553MVR80		80	82		
MPC5553MVZ132	MPC5553 324 package Lead-free (Pb-free)	132	132	–40° C	125° C
MPC5553MVZ112		112	114		
MPC5553MVZ80		80	82		
MPC5553MVM132	MPC5553 208 package Lead-free (Pb-free)	132	132	–40° C	125° C
MPC5553MVM112		112	114		
MPC5553MVM80		80	82		
MPC5553MZP132	MPC5553 416 package Leaded (SnPb)	132	132	–40° C	125° C
MPC5553MZP112		112	114		
MPC5553MZP80		80	82		
MPC5553MZQ132	MPC5553 324 package Leaded (SnPb)	132	132	–40° C	125° C
MPC5553MZQ112		112	114		
MPC5553MZQ80		80	82		

Table 1. Orderable Part Numbers (continued)

Freescale Part Number[1]	Package Description	Speed (MHz)		Operating Temperature [2]	
		Nominal	Max. [3] (f_{MAX})	Min. (T_L)	Max. (T_H)
MPC5553MVF132	MPC5553 208 package Leaded (SnPb)	132	132	–40° C	125° C
MPC5553MVF112		112	114		
MPC5553MVF80		80	82		

1 All devices are PPC5553, rather than MPC5553 or SPC5553, until product qualifications are complete. Not all configurations are available in the PPC parts.

2 The lowest ambient operating temperature is referenced by T_L; the highest ambient operating temperature is referenced by T_H.

3 Speed is the nominal maximum frequency. Max. speed is the maximum speed allowed including frequency modulation (FM). 82 MHz parts allow for 80 MHz system clock + 2% FM; 114 MHz parts allow for 112 MHz system clock + 2% FM; and132 MHz parts allow for 128 MHz system clock + 2% FM.

3 Electrical Characteristics

This section contains detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications for the MCU.

3.1 Maximum Ratings

Table 2. Absolute Maximum Ratings [1]

Spec	Characteristic	Symbol	Min.	Max.	Unit
1	1.5 V core supply voltage [2]	V_{DD}	–0.3	1.7	V
2	Flash program/erase voltage	V_{PP}	–0.3	6.5	V
4	Flash read voltage	V_{FLASH}	–0.3	4.6	V
5	SRAM standby voltage	V_{STBY}	–0.3	1.7	V
6	Clock synthesizer voltage	V_{DDSYN}	–0.3	4.6	V
7	3.3 V I/O buffer voltage	V_{DD33}	–0.3	4.6	V
8	Voltage regulator control input voltage	V_{RC33}	–0.3	4.6	V
9	Analog supply voltage (reference to V_{SSA})	V_{DDA}	–0.3	5.5	V
10	I/O supply voltage (fast I/O pads) [3]	V_{DDE}	–0.3	4.6	V
11	I/O supply voltage (slow and medium I/O pads) [3]	V_{DDEH}	–0.3	6.5	V
12	DC input voltage [4] V_{DDEH} powered I/O pads V_{DDE} powered I/O pads	V_{IN}	 –1.0 [5] –1.0 [5]	 6.5 [6] 4.6 [7]	V
13	Analog reference high voltage (reference to V_{RL})	V_{RH}	–0.3	5.5	V
14	V_{SS} to V_{SSA} differential voltage	$V_{SS} – V_{SSA}$	–0.1	0.1	V
15	V_{DD} to V_{DDA} differential voltage	$V_{DD} – V_{DDA}$	$–V_{DDA}$	V_{DD}	V
16	V_{REF} differential voltage	$V_{RH} – V_{RL}$	–0.3	5.5	V
17	V_{RH} to V_{DDA} differential voltage	$V_{RH} – V_{DDA}$	–5.5	5.5	V
18	V_{RL} to V_{SSA} differential voltage	$V_{RL} – V_{SSA}$	–0.3	0.3	V

At a known board temperature, the junction temperature is estimated using the following equation:

$$T_J = T_B + (R_{\theta JB} \times P_D)$$

where:

T_J = junction temperature (^oC)

T_B = board temperature at the package perimeter ($^oC/W$)

$R_{\theta JB}$ = junction-to-board thermal resistance ($^oC/W$) per JESD51-8

P_D = power dissipation in the package (W)

When the heat loss from the package case to the air does not factor into the calculation, an acceptable value for the junction temperature is predictable. Ensure the application board is similar to the thermal test condition, with the component soldered to a board with internal planes.

The thermal resistance is expressed as the sum of a junction-to-case thermal resistance plus a case-to-ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

$R_{\theta JA}$ = junction-to-ambient thermal resistance ($^oC/W$)

$R_{\theta JC}$ = junction-to-case thermal resistance ($^oC/W$)

$R_{\theta CA}$ = case-to-ambient thermal resistance ($^oC/W$)

$R_{\theta JC}$ is device related and is not affected by other factors. The thermal environment can be controlled to change the case-to-ambient thermal resistance, $R_{\theta CA}$. For example, change the air flow around the device, add a heat sink, change the mounting arrangement on the printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device. This description is most useful for packages with heat sinks where 90% of the heat flow is through the case to heat sink to ambient. For most packages, a better model is required.

A more accurate two-resistor thermal model can be constructed from the junction-to-board thermal resistance and the junction-to-case thermal resistance. The junction-to-case thermal resistance describes when using a heat sink or where a substantial amount of heat is dissipated from the top of the package. The junction-to-board thermal resistance describes the thermal performance when most of the heat is conducted to the printed circuit board. This model can be used to generate simple estimations and for computational fluid dynamics (CFD) thermal models.

To determine the junction temperature of the device in the application on a prototype board, use the thermal characterization parameter (Ψ_{JT}) to determine the junction temperature by measuring the temperature at the top center of the package case using the following equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

T_T = thermocouple temperature on top of the package (^oC)

Ψ_{JT} = thermal characterization parameter ($^oC/W$)

P_D = power dissipation in the package (W)

Table 6. V_{RC} and POR Electrical Specifications (continued)

Spec	Characteristic		Symbol	Min.	Max.	Units
9	Absolute value of slew rate on power supply pins		—	—	50	V/ms
10	Required gain at Tj: $I_{DD} \div I_{VRCCTL}$ (@ $f_{sys} = f_{MAX}$) 6, 7, 8, 9	– 40° C	BETA[10]	40	—	—
		25° C		45	—	—
		150° C		55	500	—

1 The internal POR signals are V_{POR15}, V_{POR33}, and V_{POR5}. On power up, assert $\overline{\text{RESET}}$ before the internal POR negates. $\overline{\text{RESET}}$ must remain asserted until the power supplies are within the operating conditions as specified in Table 9 DC Electrical Specifications. On power down, assert $\overline{\text{RESET}}$ before any power supplies fall outside the operating conditions and until the internal POR asserts.

2 V_{IL_S} (Table 9, Spec15) is guaranteed to scale with V_{DDEH6} down to V_{POR5}.

3 Supply full operating current for the 1.5 V supply when the 3.3 V supply reaches this range.

4 It is possible to reach the current limit during ramp up—do not treat this event as short circuit current.

5 At peak current for device.

6 Requires compliance with Freescale's recommended board requirements and transistor recommendations. Board signal traces/routing from the V_{RCCTL} package signal to the base of the external pass transistor and between the emitter of the pass transistor to the V_{DD} package signals must have a maximum of 100 nH inductance and minimal resistance (less than 1 Ω). V_{RCCTL} must have a nominal 1 µF phase compensation capacitor to ground. V_{DD} must have a 20 µF (nominal) bulk capacitor (greater than 4 µF over all conditions, including lifetime). Place high-frequency bypass capacitors consisting of eight 0.01 µF, two 0.1 µF, and one 1 µF capacitors around the package on the V_{DD} supply signals.

7 I_{VRCCTL} is measured at the following conditions: V_{DD} = 1.35 V, V_{RC33} = 3.1 V, V_{VRCCTL} = 2.2 V.

8 Refer to Table 1 for the maximum operating frequency.

9 Values are based on I_{DD} from high-use applications as explained in the I_{DD} Electrical Specification.

10 BETA is the worst-case external transistor BETA. It is measured on a per-part basis and calculated as ($I_{DD} \div I_{VRCCTL}$).

3.7 Power-Up/Down Sequencing

Power sequencing between the 1.5 V power supply and V_{DDSYN} or the $\overline{\text{RESET}}$ power supplies is required if using an external 1.5 V power supply with V_{RC33} tied to ground (GND). To avoid power-sequencing, V_{RC33} must be powered up within the specified operating range, even if the on-chip voltage regulator controller is not used. Refer to Section 3.7.2, "Power-Up Sequence (VRC33 Grounded)," and Section 3.7.3, "Power-Down Sequence (VRC33 Grounded)."

Power sequencing requires that V_{DD33} must reach a certain voltage where the values are read as ones before the POR signal negates. Refer to Section 3.7.1, "Input Value of Pins During POR Dependent on VDD33."

Although power sequencing is not required between V_{RC33} and V_{DDSYN} during power up, V_{RC33} must not lead V_{DDSYN} by more than 600 mV or lag by more than 100 mV for the V_{RC} stage turn-on to operate within specification. Higher spikes in the emitter current of the pass transistor occur if V_{RC33} leads or lags V_{DDSYN} by more than these amounts. The value of that higher spike in current depends on the board power supply circuitry and the amount of board level capacitance.

Furthermore, when all of the PORs negate, the system clock starts to toggle, adding another large increase of the current consumed by V_{RC33}. If V_{RC33} lags V_{DDSYN} by more than 100 mV, the increase in current consumed can drop V_{DD} low enough to assert the 1.5 V POR again. Oscillations are possible when the 1.5 V POR asserts and stops the system clock, causing the voltage on V_{DD} to rise until the 1.5 V POR negates again. All oscillations stop when V_{RC33} is powered sufficiently.

3.7.1 Input Value of Pins During POR Dependent on V_{DD33}

When powering up the device, V_{DD33} must not lag the latest V_{DDSYN} *or* $\overline{\text{RESET}}$ power pin (V_{DDEH6}) by more than the V_{DD33} lag specification listed in Table 6, spec 8. This avoids accidentally selecting the bypass clock mode because the internal versions of PLLCFG[0:1] and $\overline{\text{RSTCFG}}$ are not powered and therefore cannot read the default state when POR negates. V_{DD33} can lag V_{DDSYN} *or* the $\overline{\text{RESET}}$ power pin (V_{DDEH6}), but cannot lag both by more than the V_{DD33} lag specification. This V_{DD33} lag specification applies during power up only. V_{DD33} has no lead or lag requirements when powering down.

3.7.2 Power-Up Sequence (V_{RC33} Grounded)

The 1.5 V V_{DD} power supply must rise to 1.35 V before the 3.3 V V_{DDSYN} power supply and the $\overline{\text{RESET}}$ power supply rises above 2.0 V. This ensures that digital logic in the PLL for the 1.5 V power supply does not begin to operate below the specified operation range lower limit of 1.35 V. Because the internal 1.5 V POR is disabled, the internal 3.3 V POR or the $\overline{\text{RESET}}$ power POR must hold the device in reset. Since they can negate as low as 2.0 V, V_{DD} must be within specification before the 3.3 V POR and the $\overline{\text{RESET}}$ POR negate.

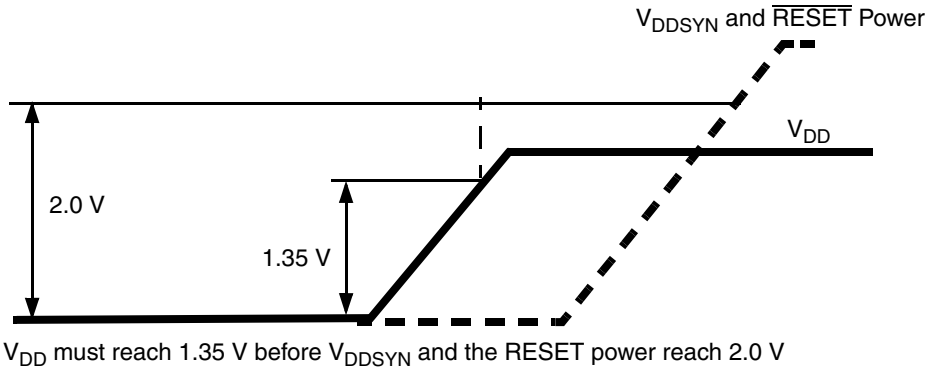


Figure 3. Power-Up Sequence (V_{RC33} Grounded)

3.7.3 Power-Down Sequence (V_{RC33} Grounded)

The only requirement for the power-down sequence with V_{RC33} grounded is if V_{DD} decreases to less than its operating range, V_{DDSYN} or the $\overline{\text{RESET}}$ power must decrease to less than 2.0 V before the V_{DD} power increases to its operating range. This ensures that the digital 1.5 V logic, which is reset only by an ORed POR and can cause the 1.5 V supply to decrease less than its specification value, resets correctly. See Table 6, footnote 1.

Table 9. DC Electrical Specifications ($T_A = T_L$ to T_H) (continued)

Spec	Characteristic	Symbol	Min	Max.	Unit
30	Operating current V_{DDE} supplies: [12] V_{DDEH1} V_{DDE2} V_{DDE3} V_{DDEH4} V_{DDE5} V_{DDEH6} V_{DDE7} V_{DDEH8} V_{DDEH9}	 I_{DD1} I_{DD2} I_{DD3} I_{DD4} I_{DD5} I_{DD6} I_{DD7} I_{DD8} I_{DD9}	 — — — — — — — — —	 Refer to footnote [12]	 mA mA mA mA mA mA mA mA mA
31	Fast I/O weak pullup current [13] 1.62–1.98 V 2.25–2.75 V 3.00–3.60 V	I_{ACT_F}	 10 20 20	 110 130 170	 µA µA µA
	Fast I/O weak pulldown current [13] 1.62–1.98 V 2.25–2.75 V 3.00–3.60 V		 10 20 20	 100 130 170	 µA µA µA
32	Slow and medium I/O weak pullup/down current [13] 3.0–3.6 V 4.5–5.5 V	I_{ACT_S}	 10 20	 150 170	 µA µA
33	I/O input leakage current [14]	I_{INACT_D}	–2.5	2.5	µA
34	DC injection current (per pin)	I_{IC}	–2.0	2.0	mA
35	Analog input current, channel off [15]	I_{INACT_A}	–150	150	nA
35a	Analog input current, shared analog / digital pins (AN[12], AN[13], AN[14], AN[15])	I_{INACT_AD}	–2.5	2.5	µA
36	V_{SS} to V_{SSA} differential voltage [16]	$V_{SS} - V_{SSA}$	–100	100	mV
37	Analog reference low voltage	V_{RL}	$V_{SSA} - 0.1$	$V_{SSA} + 0.1$	V
38	V_{RL} differential voltage	$V_{RL} - V_{SSA}$	–100	100	mV
39	Analog reference high voltage	V_{RH}	$V_{DDA} - 0.1$	$V_{DDA} + 0.1$	V
40	V_{REF} differential voltage	$V_{RH} - V_{RL}$	4.5	5.25	V
41	V_{SSSYN} to V_{SS} differential voltage	$V_{SSSYN} - V_{SS}$	–50	50	mV
42	V_{RCVSS} to V_{SS} differential voltage	$V_{RCVSS} - V_{SS}$	–50	50	mV
43	V_{DDF} to V_{DD} differential voltage	$V_{DDF} - V_{DD}$	–100	100	mV
43a	V_{RC33} to V_{DDSYN} differential voltage	$V_{RC33} - V_{DDSYN}$	–0.1	0.1 [17]	V
44	Analog input differential signal range (with common mode 2.5 V)	V_{IDIFF}	–2.5	2.5	V
45	Operating temperature range, ambient (packaged)	$T_A = (T_L$ to $T_H)$	T_L	T_H	°C
46	Slew rate on power-supply pins	—	—	50	V/ms

1 V_{DDE2} and V_{DDE3} are limited to 2.25–3.6 V only if SIU_ECCR[EBTS] = 0; V_{DDE2} and V_{DDE3} have a range of 1.6–3.6 V if SIU_ECCR[EBTS] = 1.

Table 12. FMPLL Electrical Specifications (continued)

(V_{DDSYN} = 3.0–3.6 V; V_{SS} = V_{SSSYN} = 0.0 V; T_A = T_L to T_H)

Spec	Characteristic	Symbol	Minimum	Maximum	Unit
19	CLKOUT period jitter, measured at f_{SYS} max: [13, 14] Peak-to-peak jitter (clock edge to clock edge) Long term jitter (averaged over a 2 ms interval)	C_{JITTER}	 — —	 5.0 0.01	% f_{CLKOUT}
20	Frequency modulation range limit [15] (do not exceed f_{sys} maximum)	C_{MOD}	0.8	2.4	$\%f_{SYS}$
21	ICO frequency $f_{ico} = [f_{ref\_crystal} \times (MFD + 4)] \div (PREDIV + 1)$ [16] $f_{ico} = [f_{ref\_ext} \times (MFD + 4)] \div (PREDIV + 1)$	f_{ico}	48	f_{MAX}	MHz
22	Predivider output frequency (to PLL)	f_{PREDIV}	4	20 [17]	MHz

1 Nominal crystal and external reference values are worst-case not more than 1%. The device operates correctly if the frequency remains within ± 5% of the specification limit. This tolerance range allows for a slight frequency drift of the crystals over time. The designer must thoroughly understand the drift margin of the source clock.

2 All internal registers retain data at 0 Hz.

3 Up to the maximum frequency rating of the device (refer to Table 1).

4 Loss of reference frequency is defined as the reference frequency detected internally, which transitions the PLL into self-clocked mode.

5 The PLL operates at self-clocked mode (SCM) frequency when the reference frequency falls below f_{LOR}. SCM frequency is measured on the CLKOUT ball with the divider set to divide-by-two of the system clock.
NOTE: In SCM, the MFD and PREDIV have no effect and the RFD is bypassed.

6 Use the EXTAL input high voltage parameter when using the FlexCAN oscillator in crystal mode (no quartz crystals or resonators). (V_{extal} – V_{xtal}) must be ≥ 400 mV for the oscillator's comparator to produce the output clock.

7 Use the EXTAL input low voltage parameter when using the FlexCAN oscillator in crystal mode (no quartz crystals or resonators). (V_{xtal} – V_{extal}) must be ≥ 400 mV for the oscillator's comparator to produce the output clock.

8 I_{xtal} is the oscillator bias current out of the XTAL pin with both EXTAL and XTAL pins grounded.

9 C_{PCB_EXTAL} and C_{PCB_XTAL} are the measured PCB stray capacitances on EXTAL and XTAL, respectively.

10 This specification applies to the period required for the PLL to relock after changing the MFD frequency control bits in the synthesizer control register (SYNCR). From power up with crystal oscillator reference, the lock time also includes the crystal startup time.

11 PLL is operating in 1:1 PLL mode.

12 V_{DDE} = 3.0–3.6 V.

13 Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f_{sys}. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the PLL circuitry via V_{DDSYN} and V_{SSSYN} and variation in crystal oscillator frequency increase the jitter percentage for a given interval. CLKOUT divider is set to divide-by-two.

14 Values are with frequency modulation disabled. If frequency modulation is enabled, jitter is the sum of (jitter + Cmod).

15 Modulation depth selected must not result in f_{sys} value greater than the f_{sys} maximum specified value.

16 $f_{sys} = f_{ico} \div (2^{RFD})$.

17 Maximum value for dual controller (1:1) mode is ($f_{MAX} \div 2$) with the predivider set to 1 (FMPLL_SYNCR[PREDIV] = 0b001).

3.10 eQADC Electrical Characteristics

Table 13. eQADC Conversion Specifications ($T_A = T_L$ to T_H)

Spec	Characteristic	Symbol	Minimum	Maximum	Unit
1	ADC clock (ADCLK) frequency [1]	F_{ADCLK}	1	12	MHz
2	Conversion cycles Differential Single ended	CC	 13 + 2 (15) 14 + 2 (16)	 13 + 128 (141) 14 + 128 (142)	ADCLK cycles
3	Stop mode recovery time [2]	T_{SR}	10	—	µs
4	Resolution [3]	—	1.25	—	mV
5	INL: 6 MHz ADC clock	INL6	–4	4	Counts [3]
6	INL: 12 MHz ADC clock	INL12	–8	8	Counts
7	DNL: 6 MHz ADC clock	DNL6	–3 [4]	3 [4]	Counts
8	DNL: 12 MHz ADC clock	DNL12	–6 [4]	6 [4]	Counts
9	Offset error with calibration	OFFWC	–4 [5]	4 [5]	Counts
10	Full-scale gain error with calibration	GAINWC	–8 [6]	8 [6]	Counts
11	Disruptive input injection current [7, 8, 9, 10]	I_{INJ}	–1	1	mA
12	Incremental error due to injection current. All channels are 10 kΩ < Rs <100 kΩ Channel under test has Rs = 10 kΩ, $I_{INJ} = I_{INJMAX}$, I_{INJMIN}	E_{INJ}	–4	4	Counts
13	Total unadjusted error (TUE) for single ended conversions with calibration [11, 12, 13, 14, 15]	TUE	–4	4	Counts

1 Conversion characteristics vary with F_{ADCLK} rate. Reduced conversion accuracy occurs at maximum F_{ADCLK} rate. The maximum value is based on 800 KS/s and the minimum value is based on 20 MHz oscillator clock frequency divided by a maximum 16 factor.

2 Stop mode recovery time begins when the ADC control register enable bits are set until the ADC is ready to perform conversions.

3 At $V_{RH} - V_{RL}$ = 5.12 V, one least significant bit (LSB) = 1.25, mV = one count.

4 Guaranteed 10-bit mono tonicity.

5 The absolute value of the offset error without calibration ≤ 100 counts.

6 The absolute value of the full scale gain error without calibration ≤ 120 counts.

7 Below disruptive current conditions, the channel being stressed has conversion values of: 0x3FF for analog inputs greater than V_{RH}, and 0x000 for values less than V_{RL}. This assumes that $V_{RH} \leq V_{DDA}$ and $V_{RL} \geq V_{SSA}$ due to the presence of the sample amplifier. Other channels are not affected by non-disruptive conditions.

8 Exceeding the limit can cause a conversion error on both stressed and unstressed channels. Transitions within the limit do not affect device reliability or cause permanent damage.

9 Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values using $V_{POSCLAMP} = V_{DDA}$ + 0.5 V and $V_{NEGCLAMP}$ = – 0.3 V, then use the larger of the calculated values.

10 This condition applies to two adjacent pads on the internal pad.

11 The TUE specification is always less than the sum of the INL, DNL, offset, and gain errors due to canceling errors.

12 TUE does not apply to differential conversions.

13 Measured at 6 MHz ADC clock. TUE with a 12 MHz ADC clock is: –16 counts < TUE < 16 counts.

14 TUE includes all internal device errors such as internal reference variation (75% Ref, 25% Ref).

15 Depending on the input impedance, the analog input leakage current (Table 9. DC Electrical Specifications, spec 35a) can affect the actual TUE measured on analog channels AN[12], AN[13], AN[14], AN[15].

3.11 H7Fa Flash Memory Electrical Characteristics

Table 14. Flash Program and Erase Specifications ($T_A = T_L$ to T_H)

Spec	Flash Program Characteristic	Symbol	Min.	Typical [1]	Initial Max. [2]	Max. [3]	Unit
3	Doubleword (64 bits) program time [4]	$T_{dwprogram}$	—	10	—	500	µs
4	Page program time [4]	$T_{pprogram}$	—	22	44 [5]	500	µs
7	16 KB block pre-program and erase time	$T_{16kpperase}$	—	265	400	5000	ms
9	48 KB block pre-program and erase time	$T_{48kpperase}$	—	345	400	5000	ms
10	64 KB block pre-program and erase time	$T_{64kpperase}$	—	415	500	5000	ms
8	128 KB block pre-program and erase time	$T_{128kpperase}$	—	500	1250	7500	ms
11	Minimum operating frequency for program and erase operations [6]	—	25	—	—	—	MHz

1 Typical program and erase times are calculated at 25 °C operating temperature using nominal supply values.

2 Initial factory condition: ≤ 100 program/erase cycles, 25 °C, using a typical supply voltage measured at a minimum system frequency of 80 MHz.

3 The maximum erase time occurs after the specified number of program/erase cycles. This maximum value is characterized but not guaranteed.

4 Actual hardware programming times. This does not include software overhead.

5 Page size is 256 bits (8 words).

6 The read frequency of the flash can range up to the maximum operating frequency. There is no minimum read frequency condition.

Table 15. Flash EEPROM Module Life ($T_A = T_L$ to T_H)

Spec	Characteristic	Symbol	Min.	Typical [1]	Unit
1a	Number of program/erase cycles per block for 16 KB, 48 KB, and 64 KB blocks over the operating temperature range (T_J)	P/E	100,000	—	cycles
1b	Number of program/erase cycles per block for 128 KB blocks over the operating temperature range (T_J)	P/E	1000	100,000	cycles
2	Data retention Blocks with 0–1,000 P/E cycles Blocks with 1,001–100,000 P/E cycles	Retention	 20 5	 — —	years

1 Typical endurance is evaluated at 25° C. Product qualification is performed to the minimum specification. For additional information on the Freescale definition of typical endurance, refer to engineering bulletin EB619 Typical Endurance for Nonvolatile Memory.

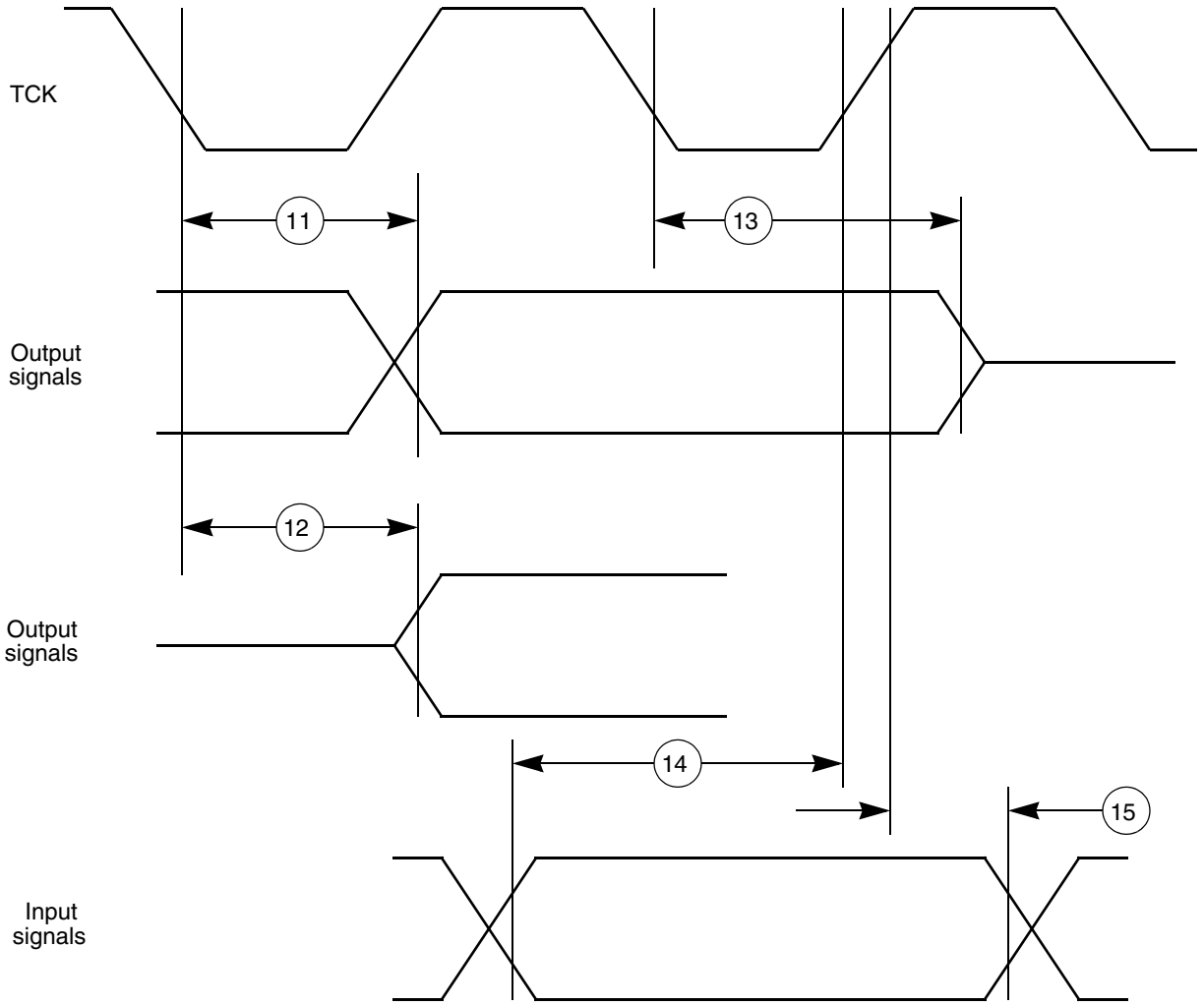


Figure 9. JTAG Boundary Scan Timing

3.13.3 Nexus Timing

Table 21. Nexus Debug Port Timing [1]

Spec	Characteristic	Symbol	Min.	Max.	Unit
1	MCKO cycle time	t_{MCYC}	1 [2]	8	t_{CYC}
2	MCKO duty cycle	t_{MDC}	40	60	%
3	MCKO low to MDO data valid [3]	t_{MDOV}	–1.5	3.0	ns
4	MCKO low to $\overline{\text{MSEO}}$ data valid [3]	t_{MSEOV}	–1.5	3.0	ns
5	MCKO low to $\overline{\text{EVTO}}$ data valid [3]	t_{EVTOV}	–1.5	3.0	ns
6	$\overline{\text{EVTI}}$ pulse width	t_{EVTIPW}	4.0	—	t_{TCYC}
7	$\overline{\text{EVTO}}$ pulse width	t_{EVTOPW}	1	—	t_{MCYC}
8	TCK cycle time	t_{TCYC}	4 [4]	—	t_{CYC}
9	TCK duty cycle	t_{TDC}	40	60	%
10	TDI, TMS data setup time	t_{NTDIS}, t_{NTMSS}	8	—	ns
11	TDI, TMS data hold time	t_{NTDIH}, t_{NTMSH}	5	—	ns
12	TCK low to TDO data valid V_{DDE} = 2.25–3.0 V V_{DDE} = 3.0–3.6 V	t_{JOV}	 0 0	 12 10	 ns ns
13	$\overline{\text{RDY}}$ valid to MCKO [5]	—	—	—	—

1 JTAG specifications apply when used for debug functionality. All Nexus timing relative to MCKO is measured from 50% of MCKO and 50% of the respective signal. Nexus timing specified at V_{DD} = 1.35–1.65 V, V_{DDE} = 2.25–3.6 V, V_{DD33} and V_{DDSYN} = 3.0–3.6 V, T_A = T_L to T_H, and CL = 30 pF with DSC = 0b10.

2 The Nexus AUX port runs up to 82 MHz. Set NPC_PCR[MCKO_DIV] to divide-by-two if the system frequency is greater than 82 MHz.

3 MDO, $\overline{\text{MSEO}}$, and $\overline{\text{EVTO}}$ data is held valid until the next MCKO low cycle occurs.

4 Limit the maximum frequency to approximately 16 MHz (V_{DDE} = 2.25–3.0 V) or 20 MHz (V_{DDE} = 3.0–3.6 V) to meet the timing specification for t_{JOV} of [0.2 x t_{JCYC}] as outlined in the IEEE-ISTO 5001-2003 specification.

5 The $\overline{\text{RDY}}$ pin timing is asynchronous to MCKO and is guaranteed by design to function correctly.

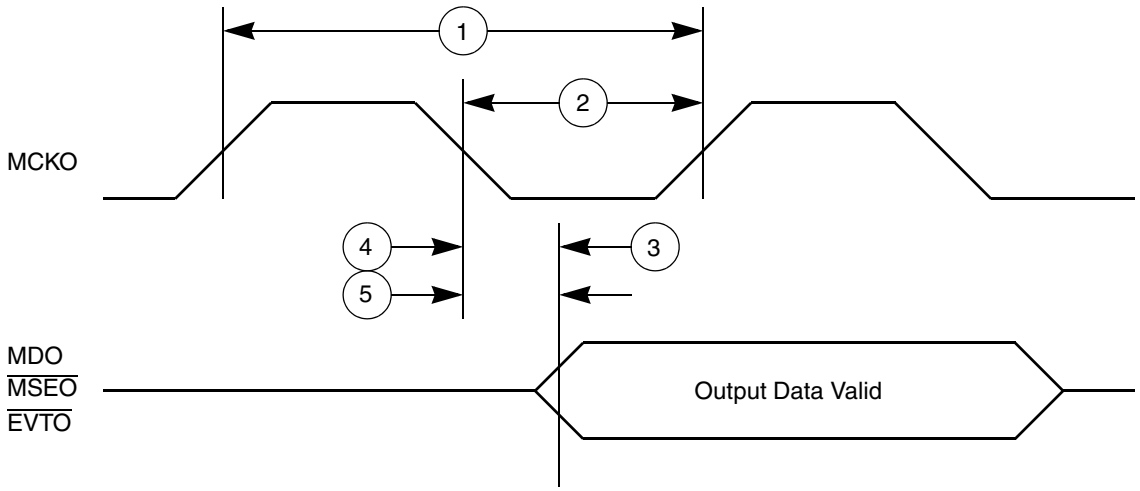


Figure 10. Nexus Output Timing

6 Due to pin limitations, the $\overline{TEA}$ signal is not available on the 324 package.

7 Due to pin limitations, the $\overline{WE}/\overline{BE}$[2:3] signals are not available on the 324 package.

8 SIU_ECCR[EBTS] = 0 timings are tested and valid at V_{DDE} = 2.25–3.6 V only; SIU_ECCR[EBTS] = 1 timings are tested and valid at V_{DDE} = 1.6–3.6 V.

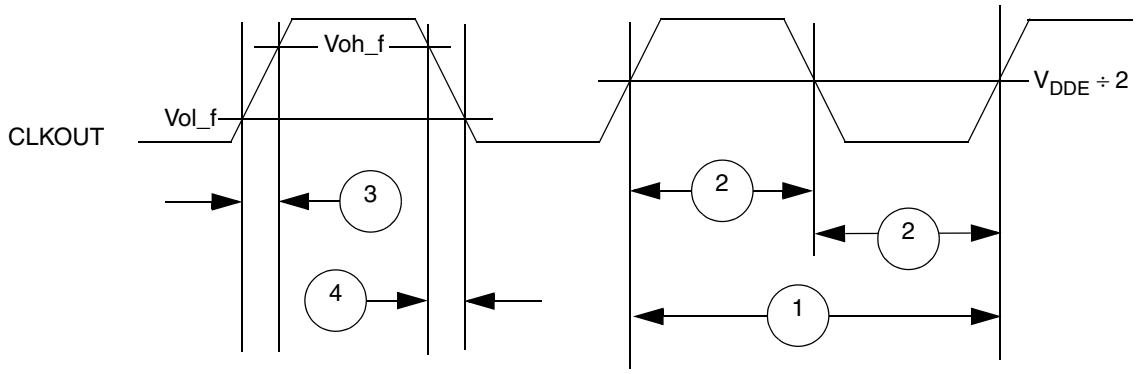


Figure 12. CLKOUT Timing

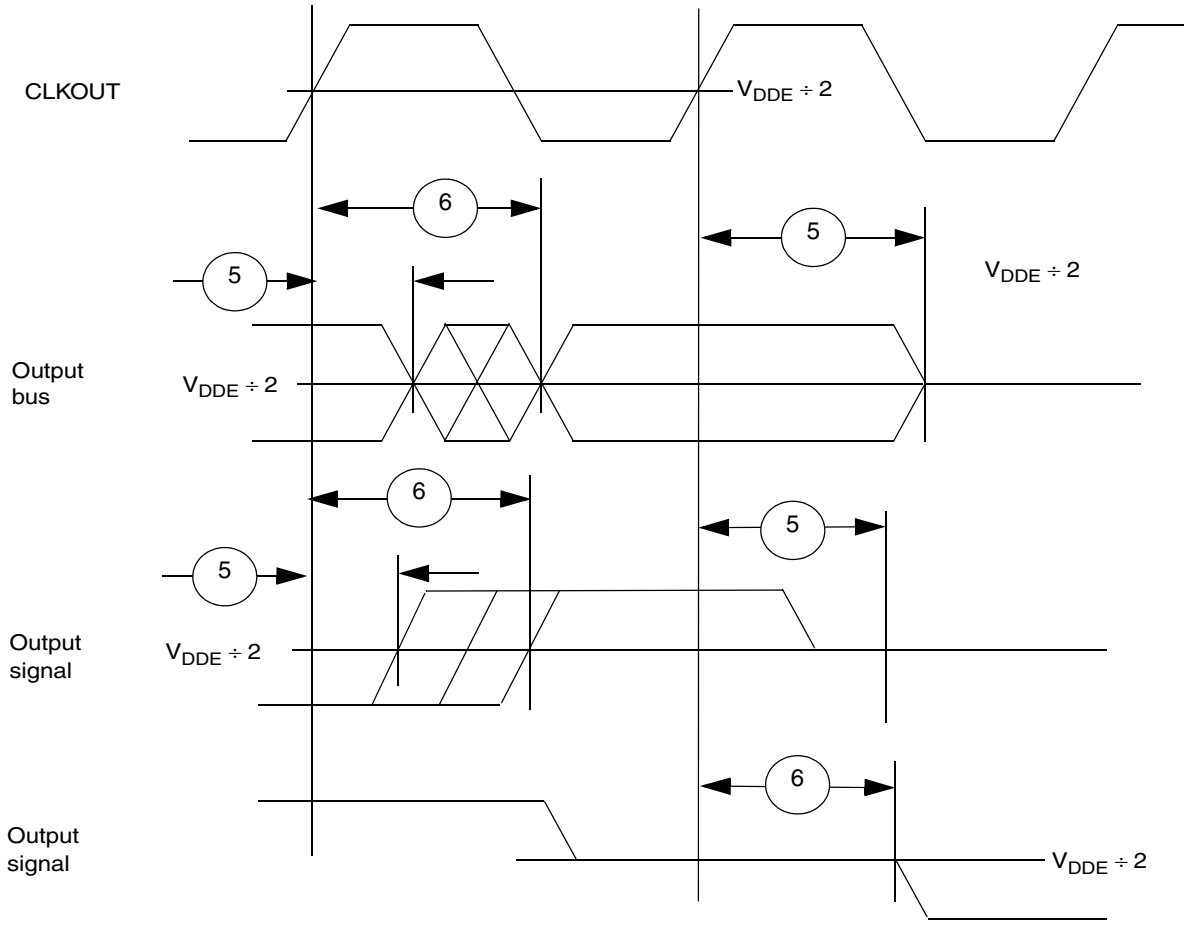


Figure 13. Synchronous Output Timing

3.14 Fast Ethernet AC Timing Specifications

Media Independent Interface (MII) Fast Ethernet Controller (FEC) signals use transistor-to-transistor logic (TTL) signal levels compatible with devices operating at 3.3 V. The timing specifications for the MII FEC signals are independent of the system clock frequency (part speed designation).

3.14.1 MII FEC Receive Signal Timing FEC_RXD[3:0], FEC_RX_DV, FEC_RX_ER, and FEC_RX_CLK

The receive functions correctly up to an FEC_RX_CLK maximum frequency of 25 MHz plus one percent. There is no minimum frequency requirement. The processor clock frequency must exceed four times the FEC_RX_CLK frequency.

Table 28 lists MII FEC receive channel timings.

Table 28. MII FEC Receive Signal Timing

Spec	Characteristic	Min.	Max	Unit
1	FEC_RXD[3:0], FEC_RX_DV, FEC_RX_ER to FEC_RX_CLK setup	5	—	ns
2	FEC_RX_CLK to FEC_RXD[3:0], FEC_RX_DV, FEC_RX_ER hold	5	—	ns
3	FEC_RX_CLK pulse-width high	35%	65%	FEC_RX_CLK period
4	FEC_RX_CLK pulse-width low	35%	65%	FEC_RX_CLK period

Figure 28 shows MII FEC receive signal timings listed in Table 28.

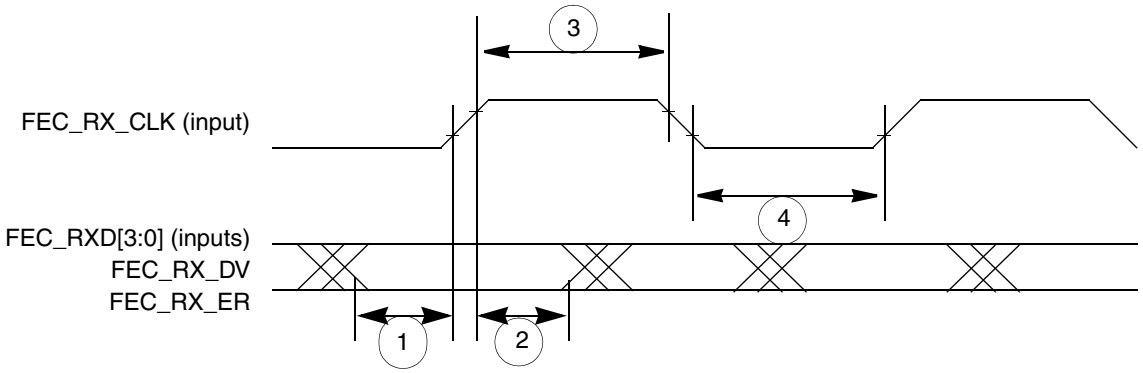


Figure 28. MII FEC Receive Signal Timing Diagram

4 Mechanicals

4.1 MPC5553 208 MAP BGA Pinout

Figure 32 is a pinout for the MPC5553 208 MAP BGA package.

NOTE.

V_{DDEH10} and V_{DDEH6} are connected internally on the 208-ball package and are listed as V_{DDEH6}.

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	
A	VSS	AN9	AN11	VDDA1	VSSA1	AN1	AN5	VRH	VRL	AN27	VSSA0	AN12	MDO2	MDO0	VDD33	VSS	A
B	VDD	VSS	AN38	AN21	AN0	AN4	REF BYPC	AN22	AN25	AN28	VDDA0	AN13	MDO3	MDO1	VSS	VDD	B
C	VSTBY	VDD	VSS	AN17	AN34	AN16	AN3	AN7	AN23	AN32	AN33	AN14	AN15	VSS	MSEO0	TCK	C
D	VDD33	AN39	VDD	VSS	AN18	AN2	AN6	AN24	AN30	AN31	AN35	VDDEH 9	VSS	TMS	EVTO	TEST	D
E	ETPUA 30	ETPUA 31	AN37	VDD									VDDE7	TDI	EVTI	MSEO1	E
F	ETPUA 28	ETPUA 29	ETPUA 26	AN36									VDDEH 6	TDO	MCKO	JCOMP	F
G	ETPUA 24	ETPUA 27	ETPUA 25	ETPUA 21			VSS	VSS	VSS	VSS			SOUTB	PCSB3	SINB	PCSB0	G
H	ETPUA 23	ETPUA 22	ETPUA 17	ETPUA 18			VSS	VSS	VSS	VSS			PCSA3	PCSB4	PCSB2	PCSB1	H
J	ETPUA 20	ETPUA 19	ETPUA 14	ETPUA 13			VSS	VSS	VSS	VSS			PCSB5	TXDA	PCSA2	SCKB	J
K	ETPUA 16	ETPUA 15	ETPUA 7	VDDEH 1			VSS	VSS	VSS	VSS			CNTXC	RXDA	RSTOUT	VPP	K
L	ETPUA 12	ETPUA 11	ETPUA 6	TCRCLK A									TXDB	CNRXC	WKP CFG	RESET	L
M	ETPUA 10	ETPUA 9	ETPUA 1	ETPUA 5									RXDB	PLL CFG0	BOOT CFG1	VSS SYN	M
N	ETPUA 8	ETPUA 4	ETPUA 0	VSS	VDD	VDD33	EMIOS 2	EMIOS 10	VDDEH 4	EMIOS 12	EMIOS 21	VDD33	VSS	VRC CTL	PLL CFG1	EXTAL	N
P	ETPUA 3	ETPUA 2	VSS	VDD	GPIO 207	VDDE2	EMIOS 6	EMIOS 8	EMIOS 16	EMIOS 17	EMIOS 22	CNTXA	VDD	VSS	VRC33	XTAL	P
R	CS0	VSS	VDD	GPIO 206	EMIOS 4	EMIOS 3	EMIOS 9	EMIOS 11	EMIOS 14	EMIOS 19	EMIOS 23	CNRXA	CNRXB	VDD	VSS	VDD SYN	R
T	VSS	VDD	OE	EMIOS 0	EMIOS 1	EMIOS 5	EMIOS 7	EMIOS 13	EMIOS 15	EMIOS 18	EMIOS 20	CNTXB	VDDE5	ENG CLK	VDD	VSS	T
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	

Figure 32. MPC5553 208 Package

4.2 MPC5553 324 PBGA Pinouts

Figure 33 is a pinout for the MPC5553 324 PBGA package.

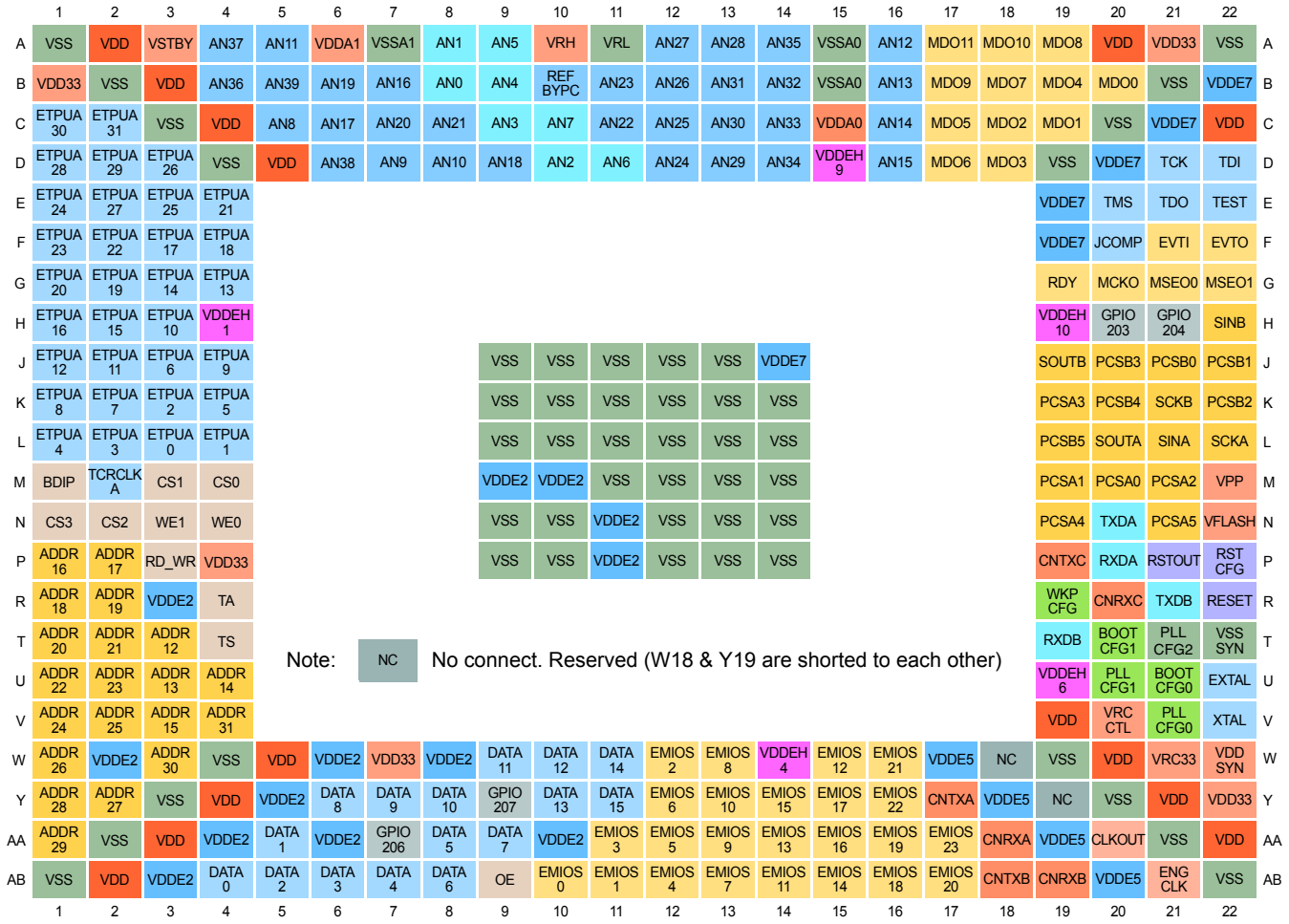


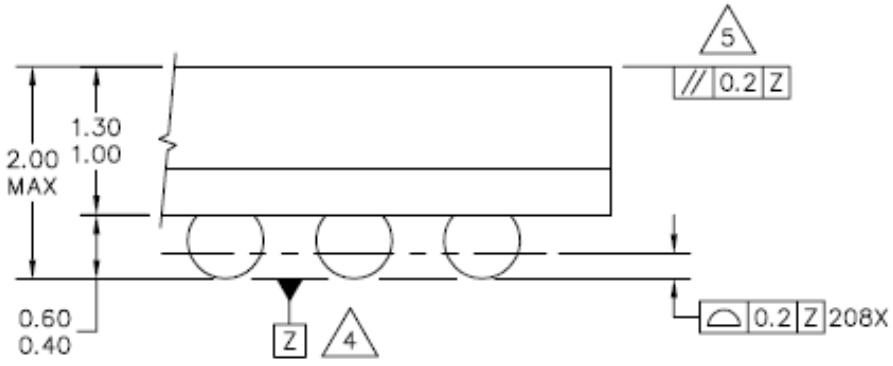
Figure 33. MPC5553 324 Package

4.3 MPC5553 416 PBGA Pinout

Figure 34, Figure 35, and Figure 36 show the pinout for the MPC5553 416 PBGA package. The alternate Fast Ethernet Controller (FEC) signals are multiplexed with the data calibration bus signals.

NOTE

The MPC5500 devices are pin compatible for software portability and use the primary function names to label the pins in the BGA diagram. Although some devices do not support all the primary functions shown in the BGA diagram, the muxed and GPIO signals on those pins remain available. See the signals chapter in the device reference manual for the signal muxing.



DETAIL K
(ROTATED 90° CLOCKWISE)

NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M–1994.
3. DIMENSION b IS MEASURED AT THE MAXIMUM SOLDER BALL DIAMETER, PARALLEL TO DATUM PLANE Z.
4. DATUM Z (SEATING PLANE) IS DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.
5. PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.

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TITLE: 208 I/O MAP BGA, 17 X 17 PKG, 1–MM PITCH	DOCUMENT NO: 98ARS23882W	REV: D
	CASE NUMBER: 1159A–01	02 AUG 2005
	STANDARD: JEDEC MO–151 AAF–1	

Figure 37. MPC5553 208 MAP BGA Package (continued)

NOTES:

1. ALL DIMENSIONS IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M–1994.
3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.
4. DATUM A, THE SEATING PLANE, IS DETERMINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.
5. PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.

MECHANICAL OUTLINE	PRINT VERSION NOT TO SCALE

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PBGA, 324 I/O, 23 X 23 PKG, 1 MM PITCH (OMPAC)	CASE NUMBER: 1158–03	26 APR 2006
	STANDARD: JEDEC MS–034 AAJ–1	

Figure 38. MPC5553 324 TEPBGA Package (continued)

NOTES:

1. ALL DIMENSIONS IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M–1994.
3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.
4. DATUM A, THE SEATING PLANE, IS DETERMINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.

	MECHANICAL OUTLINE	PRINT VERSION NOT TO SCALE
TITLE: 416 I/O, PBGA 27 X 27 PKG, 1 MM PITCH (OMPAC)	DOCUMENT NO: 98ARE10523D	REV: A
	CASE NUMBER: 1494–01	13 JUL 2005
	STANDARD: JEDEC MS–034 AAL–1	

Figure 39. MPC5553 416 TEPBGA Package (continued)

Table 33. Table and Figure Changes Between Rev. 2.0 and 3.0

Location	Description of Changes
Figure 1 MPC5500 Family Part Numbers:	• Removed the 2 in the tape and reel designator in both the graphic and in the Tape and Reel Status text. • Changed Qualification Status by adding ', general market flow' to the M designator, and added an 'S' designator with the description of 'Fully spec. qualified, automotive flow.
Table 1 (Orderable Part Numbers) Orderable Part Numbers:	• Moved the 'Lead-free' or 'Lead' in the Package Description column to a second line and added 'Pb-free' and 'SnPb' respectively. Changed Lead to Leaded. • Footnote 2 changed to read:' The lowest ambient operating temperature is referenced by T_L; the highest ambient operating temperature is referenced by T_H.' • Footnote 3 changed to read: 'Speed is the nominal maximum frequency. Max speed is the maximum speed allowed including frequency modulation (FM): 82 MHz parts allow for 80 MHz system clock + 2% FM; 114 MHz parts allow for 112 MHz system clock + 2% FM; and 132 MHz parts allow for 128 MHz system clock + 2% FM;.'
Table 2 (Absolute Maximum Ratings) Absolute Maximum Ratings:	• Deleted Spec 3, "Flash core voltage." • Spec 21, Added the name of the spec, '*V_{RC33} to V_{DDSYN} differential voltage,'* as well as the name and cross reference to Table 9, *DC Electrical Specification*s, to which the Spec was moved. • Spec 28 "Maximum Solder Temperature": Added two lines: Lead-free (Pb-free) and Leaded (SnPb) with maximum values of 260 C and 245 C respectively. • Footnote 1, added: 'any of' between 'beyond' and 'the listed maxima.' • Deleted footnote 2: 'Absolute maximum voltages are currently maximum burn-in voltages. Absolute maximum specifications for device stress have not yet been determined.' • Footnote 6 (now footnote 5): Changed to the following sentence to the end, "Internal structures hold the input voltage greater than -1.0 V if the injection current limit of 2 mA is met. Keep the negative DC voltage greater than -0.6 V on eTPU[15] and on SINB during the internal power-on reset (POR) state."
Table 4 (EMI Testing Specifications) EMI Testing Specifications: Changed the maximum operating frequency to from 132 to f_{MAX}.	
Table 5 (ESD Ratings ,) ESD Characteristics: Added *(Electromagnetic Static Discharge)* in the section title.	

Table 6 (V_{RC} and POR Electrical Specifications), VCR/POR Electrical Specifications:	• Subscript all symbol names that appear after the first underscore character.
	• Removed 'Tj 'after '150 C' in the last line, second column: Characteristic.
	• Reformatted columns.
	• Added footnote 1 to specs 1, 2, and 3 that reads: On power up, assert $\overline{\text{RESET}}$ before V_{POR15}, V_{POR33}, and V_{POR5} negate (internal POR). RESET must remain asserted until the power supplies are within the operating conditions as specified in Table 9 (DC Electrical Specifications ($T_A = T_L$ to T_H)) *DC Electrical Specifications*. On power down, assert $\overline{\text{RESET}}$ before any power supplies fall outside the operating conditions and until the internal POR asserts.
	• Added to Spec 2:
	3.3 V (V_{DDSYN}) POR negated (ramp down) Min. 0.0 Max 0.30 V
	3.3 V (V_{DDSYN}) POR asserted (ramp up) Min. 0.0 Max 0.30 V
	• Specs 7 and 10: added 'at Tj 'at the end of the first line in the second column: Characteristic.
	• Spec 10:
	  • Changed the minimum values of: -40 C = 40; 25 C = 45; 150 C = 55.
	  • Added cross-reference to footnote 6: 'I_{VRCCTL} is measured at the following conditions: V_{DD} = 1.35 V, V_{RC33} = 3.1 V, V_{VRCCTL} = 2.2 V.' Changed '(@ V_{DD} = 1.35 V, $f_{sys} = f_{MAX}$)'to '(@ $f_{sys} = f_{MAX}$).
	• Added a new footnote 7, 'Refer to Table 1 (Orderable Part Numbers) for the maximum operating frequency.'
	• Rewrote old footnote 8 (new footnote 9) to read: Represents the worst-case external transistor BETA. It is measured on a per-part basis and calculated as ($I_{DD} \div I_{VRCCTL}$).
	• Deleted old footnote 9: 'Preliminary value. Final specification pending characterization.'

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